

**Vishay Semiconductors** 

### 6-Line ESD-Protection Diode Array in LLP75

#### Features

- Ultra compact LLP75-7L package
- 6-line ESD-protection
- Low leakage current I<sub>R</sub> < 0.1 μA</li>
- Low load capacitance C<sub>D</sub> = 13 pF
- ESD-immunity acc. IEC 61000-4-2
  - ± 15 kV contact discharge ± 15 kV air discharge
- Working voltage range V<sub>RWM</sub> = 5 V
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### Marking (example only)



Dot = Pin 1 marking XX = Date code YY = Type code (see table below)

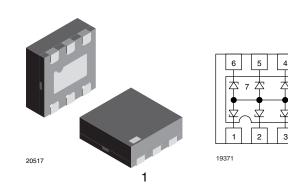
#### **Ordering Information**

Device name	Device name Ordering code		Minimum order quantity		
VESD05A6A-HAF	VESD05A6A-HAF-GS08	3000	15000		

#### Package Data

Device name	Package name	Type code	Weight	Molding compound flammability rating	Moisture sensitivity level	Soldering conditions
VESD05A6A-HAF	LLP75-7L	AT	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 $^{\circ}\text{C}/10$ s at terminals

\*\* Please see document "Vishay Material Category Policy" www.vishay.com/doc?99902







# VESD05A6A-HAF

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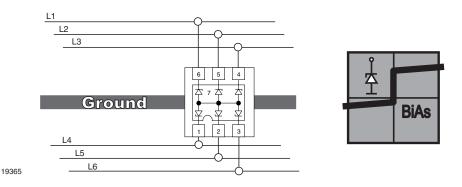


#### **Absolute Maximum Ratings**

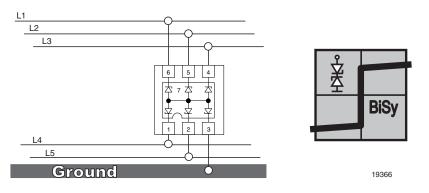
Rating	Test condition	Symbol	Value	Unit	
Peak pulse current	BiAs-Mode: each input (pin 1 - pin 6) to ground (pir acc. IEC 61000-4-5; t <sub>p</sub> = 8/20 μs; single shot	I <sub>PPM</sub>	2.5	А	
	BiSy-mode: each input (pin 1 - pin 6) to any other inp Pin 2 not connected. Acc. IEC 61000-4-5; $t_p = 8/20 \ \mu s$ ; s	I <sub>PPM</sub>	2.5	А	
Peak pulse power	BiAs-mode: each input (pin 1 - pin 6) to ground (pir acc. IEC 61000-4-5; t <sub>p</sub> = 8/20 μs; single shot	P <sub>PP</sub>	33	W	
	BiSy-mode: each input (pin 1 - pin 6) to any other inp Pin 2 not connected. Acc. IEC 61000-4-5; $t_p = 8/20 \ \mu s$ ; s	P <sub>PP</sub>	43	W	
ESD immunity	Acc. IEC61000-4-2; 10 pulses BiAs-mode: each input (pin 1 - pin 6) to ground (pin 2)	Contact discharge	V <sub>ESD</sub>	± 15	kV
		Air discharge	$V_{ESD}$	± 15	kV
	Acc. IEC 61000-4-2 ; 10 pulses BiSy-mode: each input (pin 1 - pin 6) to any other input pin.	Contact discharge	$V_{ESD}$	± 10	kV
	Pin 2 not connected	Air discharge	$V_{ESD}$	± 10	kV
Operating temperature	Junction temperature			- 40 to + 125	°C
Storage temperature				- 55 to + 150	°C

#### **Application Note:**

a) With the VESD05A6A-HAF 6 different signal or data lines can be clamped to ground. Due to the different clamping levels in forward and reverse direction the VESD05A6A-HAF clamping behavior is <u>Bi</u>directional and <u>Asymmetrical</u> (BiAs).



b) If symmetrical clamping behaviour is required the **VESD05A6A-HAF** can also be used as a <u>**Bi**</u>directional <u>**Sy**</u>mmetrical protection device protecting up to 5 lines. In this case pin no. 7 must not be connected.



For technical support, please contact: ESDprotection@vishay.com



#### **Vishay Semiconductors**

#### **Electrical Characteristics**

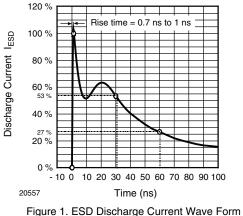
Ratings at 25 °C, ambient temperature unless otherwise specified

#### VESD05A6A-HAF

BiAs mode (between pin 1, 2, 3, 4, 5 or 6 and pin 7)

Parameter	Test conditions/remarks Symbol		Min.	Тур.	Max.	Unit
Protection paths	Number of lines which can be protected	N <sub>lines</sub>			6	lines
Reverse stand off voltage	at I <sub>R</sub> = 0.1 μA	V <sub>RWM</sub>	5			V
Max. reverse current	at V <sub>R</sub> = 5 V	I <sub>R</sub>		< 0.01	0.1	μA
Reverse break down voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	6	6.7	7.5	V
Reverse clamping voltage	at I <sub>PP</sub> = 1 A	V <sub>C</sub>		9	10	V
	at I <sub>PP</sub> = I <sub>PPM</sub> = 2.5 A	V <sub>C</sub>		12	13	V
Forward clamping voltage	at I <sub>PP</sub> = 1 A	V <sub>F</sub>		2	2.5	V
	at I <sub>PP</sub> = I <sub>PPM</sub> = 2.5 A	V <sub>F</sub>		3.2	4	V
Line capacitance	at V <sub>R</sub> = 0 V; f = 1 MHz	CD		13	15	pF
	at V <sub>R</sub> = 2.5 V; f = 1 MHz	CD		8		pF

**Typical Characteristics** T<sub>amb</sub> = 25 °C, unless otherwise specified



acc. IEC 61000-4-2 (330 Ω/150 pF)

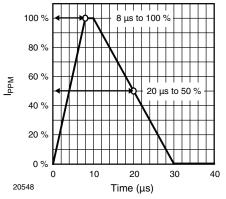


Figure 2. 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

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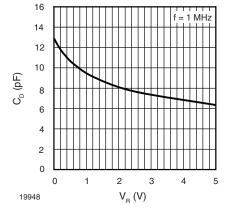


Figure 3. Typical Capacitance C<sub>D</sub> vs. Reverse Voltage V<sub>R</sub>

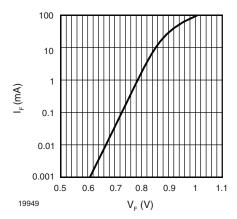


Figure 4. Typical Forward Current  $\rm I_F$  vs. Forward Voltage  $\rm V_F$ 

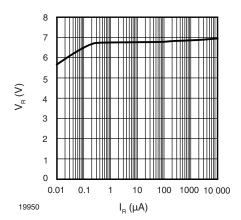


Figure 5. Typical Reverse Voltage  $V_R$  vs. Reverse Current  $I_R$ 

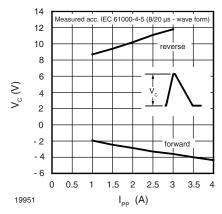


Figure 6. Typical Clamping Voltage vs. Peak Pulse Current IPP

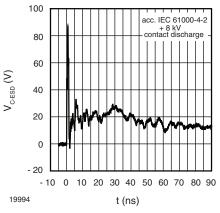


Figure 7. Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

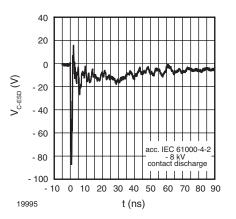


Figure 8. Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)



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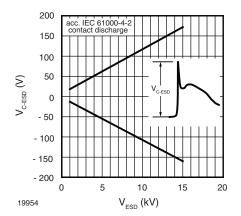
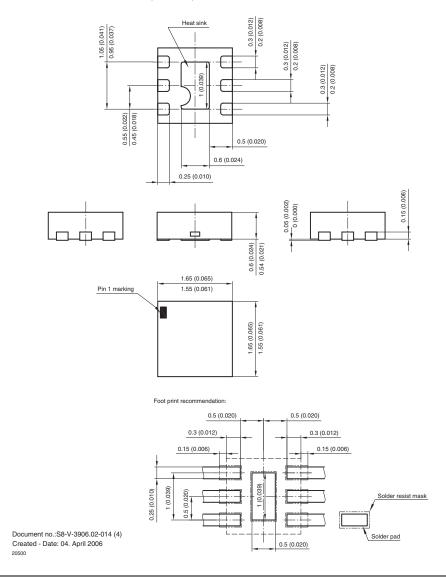


Figure 9. Typical max. Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)







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